

NOTICE OF REVISION (NOR)				1. DATE (YYMMDD) 96-10-04		Form Approved OMB No. 0704-0188			
THIS REVISION DESCRIBED BELOW HAS BEEN AUTHORIZED FOR THE DOCUMENT LISTED.									
<small>Public reporting burden for this collection is estimated to average 2 hours per response, including the time for reviewing instructions, searching existing data sources, gathering and maintaining the data needed, and completing and reviewing the collection of information. Send comments regarding this burden estimate or any other aspect of this collection of information, including suggestions for reducing this burden, to Department of Defense, Washington Headquarters Services, Directorate for Information Operations and Reports, 1215 Jefferson Davis Highway, Suite 1204, Arlington, VA 22202-4302, and to the Office of Management and Budget, Paperwork Reduction Project (0704-0188), Washington, DC 20503. PLEASE DO NOT RETURN YOUR COMPLETED FORM TO EITHER OF THESE ADDRESSES. RETURN COMPLETED FORM TO THE GOVERNMENT ISSUING CONTRACTING OFFICER FOR THE CONTRACT/ PROCURING ACTIVITY NUMBER LISTED IN ITEM 2 OF THIS FORM.</small>						2. PROCURING ACTIVITY NO.			
						3. DODAAC			
4. ORIGINATOR		b. ADDRESS (Street, City, State, Zip Code) Defense Supply Center Columbus 3990 Broad Street Columbus, OH 43216-5000		5. CAGE CODE 67268		6. NOR NO. 5962-R009-97			
a. TYPED NAME (First, Middle Initial, Last)				7. CAGE CODE 67268		8. DOCUMENT NO. 5962-94730			
9. TITLE OF DOCUMENT MICROCIRCUIT, MEMORY, DIGITAL CMOS, PROGRAMMABLE LOGIC CELL ARRAY, MONOLITHIC SILICON				10. REVISION LETTER		11. ECP NO.			
				a. CURRENT B b. NEW C					
12. CONFIGURATION ITEM (OR SYSTEM) TO WHICH ECP APPLIES All									
13. DESCRIPTION OF REVISION									
<p>Sheet 1: Revisions ltr column; add "C". Revisions description column; add "Changes in accordance with NOR 5962-R009-97". Revisions date column; add "96-10-04". Rev status above sheet number 1 delete "B", and add "C", and above sheet number 15, add "C". Revision level block; delete "B", and add "C".</p> <p>Sheet 15: Table I, footnote 5/ Delete the last sentence of this footnote and replace it with the following: "Characterization data is taken initially and after any design or process change which may affect this parameter." Revision level block; add "C".</p>									
14. THIS SECTION FOR GOVERNMENT USE ONLY									
a. (X one)		<input checked="checked" type="checkbox"/> (1) Existing document supplemented by the NOR may be used in manufacture. <input type="checkbox"/> (2) Revised document must be received before manufacturer may incorporate this change. <input type="checkbox"/> (3) Custodian of master document shall make above revision and furnish revised document.							
								X	
b. ACTIVITY AUTHORIZED TO APPROVE CHANGE FOR GOVERNMENT DSCC-VAS				c. TYPED NAME (First, Middle Initial, Last) Ray Monnin					
d. TITLE Microelectronics Team Chief			e. SIGNATURE Ray Monnin			f. DATE SIGNED (YYMMDD) 96-10-04			
15a. ACTIVITY ACCOMPLISHING REVISION DSCC-VAS			b. REVISION COMPLETED (Signature) Kenneth S. Rice			c. DATE SIGNED (YYMMDD) 96-10-04			

NOTICE OF REVISION (NOR)			1. DATE (YYMMDD) 95-08-25		Form Approved OMB No. 0704-0188								
THIS REVISION DESCRIBED BELOW HAS BEEN AUTHORIZED FOR THE DOCUMENT LISTED.													
<small>Public reporting burden for this collection is estimated to average 2 hours per response, including the time for reviewing instructions, searching existing data sources, gathering and maintaining the data needed, and completing and reviewing the collection of information. Send comments regarding this burden estimate or any other aspect of this collection of information, including suggestions for reducing this burden, to Department of Defense, Washington Headquarters Services, Directorate for Information Operations and Reports, 1215 Jefferson Davis Highway, Suite 1204, Arlington, VA 22202-4302, and to the Office of Management and Budget, Paperwork Reduction Project (0704-0188), Washington, DC 20503. PLEASE DO NOT RETURN YOUR COMPLETED FORM TO EITHER OF THESE ADDRESSED. RETURN COMPLETED FORM TO THE GOVERNMENT ISSUING CONTRACTING OFFICER FOR THE CONTRACT/ PROCURING ACTIVITY NUMBER LISTED IN ITEM 2 OF THIS FORM.</small>					2. PROCURING ACTIVITY NO.								
					3. DODAAC								
4. ORIGINATOR		b. ADDRESS (Street, City, State, Zip Code) 1507 Wilmington Pike Dayton, OH 45444-5765		5. CAGE CODE 67268		6. NOR NO. 5962-R186-95							
a. TYPED NAME (First, Middle Initial, Last) Defense Electronics Supply Center				7. CAGE CODE 67268		8. DOCUMENT NO. 5962-94730							
9. TITLE OF DOCUMENT MICROCIRCUIT, MEMORY, DIGITAL, CMOS, PROGRAMMABLE LOGIC ARRAY, MONOLITHIC SILICON				10. REVISION LETTER		11. ECP NO. N/A							
		a. CURRENT A		b. NEW B									
12. CONFIGURATION ITEM (OR SYSTEM) TO WHICH ECP APPLIES All													
13. DESCRIPTION OF REVISION													
<p>Sheet 1: Revisions ltr column; add "B". Revisions description column; add "Changes in accordance with NOR 5962-R186-95". Revisions date column; add "95-08-25". Revision level block; change from "A" to "B". Rev status of sheets; for sheet 1, change from "A" to "B". For sheet 6, add "B".</p> <p>Sheet 21: For case outline X, terminal number K15 change terminal symbol from I/O to GND. Revision level block; add "B".</p>													
14. THIS SECTION FOR GOVERNMENT USE ONLY													
a. (X one)		<table border="1" style="width: 100%; border-collapse: collapse;"> <tr> <td style="width: 5%; text-align: center;">X</td> <td>(1) Existing document supplemented by the NOR may be used in manufacture.</td> </tr> <tr> <td style="text-align: center;"></td> <td>(2) Revised document must be received before manufacturer may incorporate this change.</td> </tr> <tr> <td style="text-align: center;"></td> <td>(3) Custodian of master document shall make above revision and furnish revised document.</td> </tr> </table>						X	(1) Existing document supplemented by the NOR may be used in manufacture.		(2) Revised document must be received before manufacturer may incorporate this change.		(3) Custodian of master document shall make above revision and furnish revised document.
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	(2) Revised document must be received before manufacturer may incorporate this change.												
	(3) Custodian of master document shall make above revision and furnish revised document.												
b. ACTIVITY AUTHORIZED TO APPROVE CHANGE FOR GOVERNMENT DESC-ELDS				c. TYPED NAME (First, Middle Initial, Last) Michael A. Frye									
d. TITLE Chief, Microelectronics Branch			e. SIGNATURE Michael A. Frye			f. DATE SIGNED (YYMMDD) 95-08-25							
15a. ACTIVITY ACCOMPLISHING REVISION DESC-ELDS			b. REVISION COMPLETED (Signature) Kenneth Rice			c. DATE SIGNED (YYMMDD) 95-08-25							

NOTICE OF REVISION (NOR)

1. DATE
(YYMMDD)
95-06-16

Form Approved
OMB No. 0704-0188

This revision described below has been authorized for the document listed.

Public reporting burden for this collection is estimated to average 2 hours per response, including the time for reviewing instructions, searching existing data sources, gathering and maintaining the data needed, and completing and reviewing the collection of information. Send comments regarding this burden estimate or any other aspect of this collection of information, including suggestions for reducing this burden, to Department of Defense, Washington Headquarters Services, Directorate for Information Operations and Reports, 1215 Jefferson Davis Highway, Suite 1204, Arlington, VA 22202-4302, and to the Office of Management and Budget, Paperwork Reduction Project (0704-0188), Washington, DC 20503. PLEASE DO NOT RETURN YOUR COMPLETED FORM TO EITHER OF THESE ADDRESSES. RETURN COMPLETED FORM TO THE GOVERNMENT ISSUING CONTRACTING OFFICER FOR THE CONTRACT/ PROCURING ACTIVITY NUMBER LISTED IN ITEM 2 OF THIS FORM.

2. PROCURING
ACTIVITY NO.

3. DODAAC

4. ORIGINATOR

b. ADDRESS (Street, City, State, Zip Code)

5. CAGE CODE

6. NOR NO.

a. TYPED NAME (First, Middle Initial,
Last)

1507 Wilmington Pike
Dayton, OH 45444-5270

67268

5962-R156-95

Defense Electronics Supply Center

7. CAGE CODE

8. DOCUMENT NO.

67268

5962-94730

9. TITLE OF DOCUMENT

MICROCIRCUIT, MEMORY, DIGITAL, CMOS, PROGRAMMABLE LOGIC ARRAY,
MONOLITHIC SILICON

10. REVISION LETTER

a. CURRENT

b. NEW

A

11. ECP NO.

12. CONFIGURATION ITEM (OR SYSTEM) TO WHICH ECP APPLIES

13. DESCRIPTION OF REVISION

Sheet 1: Revisions ltr column; add "A".
Revisions description column; add "Changes in accordance with NOR 5962-R156-95".
Revisions date column; add "95-06-16".
Revision level block; add "A".
Rev status of sheets; For sheets 1,6, add "A".

Sheet 6: Input capacitance C_{IN} change the max column from 15 to 16.
Revision level block; add "A".

14. THIS SECTION FOR GOVERNMENT USE ONLY

a. (X one)

X

(1) Existing document supplemented by the NOR may be used in manufacture.

(2) Revised document must be received before manufacturer may incorporate this change.

(3) Custodian of master document shall make above revision and furnish revised document.

b. ACTIVITY AUTHORIZED TO APPROVE CHANGE FOR GOVERNMENT

c. TYPED NAME (First, Middle Initial, Last)

DESC-ELDS

Kenneth S. Rice

d. TITLE

e. SIGNATURE

f. DATE SIGNED
(YYMMDD)

Microelectronics Branch Chief

Michael A. Frye

95-06-16

15a. ACTIVITY ACCOMPLISHING REVISION

b. REVISION COMPLETED (Signature)

c. DATE SIGNED
(YYMMDD)

DESC-ELDS

Kenneth S. Rice

95-06-16

REVISIONS

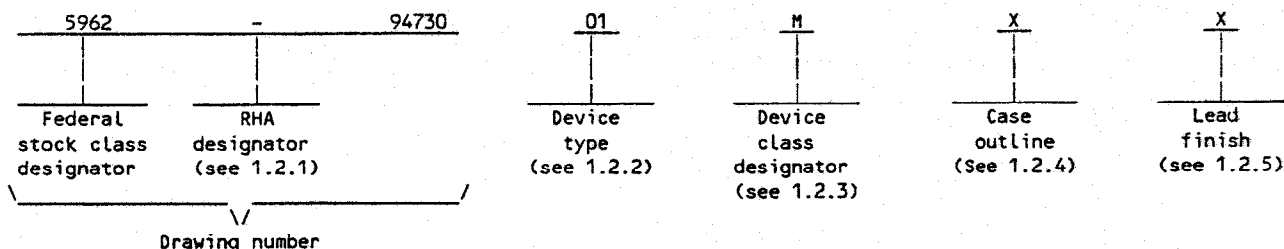
LTR	DESCRIPTION																DATE (YR-MO-DA)	APPROVED

REV																													
SHEET																													
REV	35	36																											
SHEET	15	16	17	18	19	20	21	22	23	24	25	26	27	28	29	30	31	32	33	34									
REV STATUS OF SHEETS				REV																									
				SHEET			1	2	3	4	5	6	7	8	9	10	11	12	13	14									
PMIC N/A				PREPARED BY Kenneth Rice						DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444																			
STANDARD MICROCIRCUIT DRAWING THIS DRAWING IS AVAILABLE FOR USE BY ALL DEPARTMENTS AND AGENCIES OF THE DEPARTMENT OF DEFENSE AMSC N/A				CHECKED BY Jeff Bowling																									
				APPROVED BY Michael Frye																									
				DRAWING APPROVAL DATE 94-11-21																									
				REVISION LEVEL																									
										SIZE A	CAGE CODE 67268	5962-94730																	
										SHEET 1 OF 36																			

1. SCOPE

1.1 Scope. This drawing forms a part of a one part - one part number documentation system (see 6.6 herein). Two product assurance classes consisting of military high reliability (device classes Q and M) and space application (device class V), and a choice of case outlines and lead finishes are available and are reflected in the Part or Identifying Number (PIN). Device class M microcircuits represent non-JAN class B microcircuits in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices". When available, a choice of Radiation Hardness Assurance (RHA) levels are reflected in the PIN.

1.2 PIN. The PIN shall be as shown in the following example:



1.2.1 RHA designator. Device class M RHA marked devices shall meet the MIL-I-38535 appendix A specified RHA levels and shall be marked with the appropriate RHA designator. Device classes Q and V RHA marked devices shall meet the MIL-I-38535 specified RHA levels and shall be marked with the appropriate RHA designator. A dash (-) indicates a non-RHA device.

1.2.2 Device type(s). The device type(s) shall identify the circuit function as follows:

Device type	Generic number	Circuit function	Access time
01	4013-10	13000 gate programmable array	10 ns
02	4013-6	13000 gate programmable array	6 ns

1.2.2 Device class designator. The device class designator shall be a single letter identifying the product assurance level as follows:

Device class	Device requirements documentation
M	Vendor self-certification to the requirements for non-JAN class B microcircuits in accordance with 1.2.1 of MIL-STD-883
Q or V	Certification and qualification to MIL-I-38535

1.2.4 Case outline(s). The case outline(s) shall be as designated in MIL-STD-1835 and as follows:

Outline letter	Descriptive designator	Terminals	Package style
X	CMGA10-P223	223	Pin grid array package
Y	see figure 1	228	Quad flat package
Z	see figure 1	228	Quad flat package

1.2.4 Lead finish. The lead finish shall be as specified in MIL-STD-883 (see 3.1 herein) for class M or MIL-I-38535 for classes Q and V. Finish letter "X" shall not be marked on the microcircuit or its packaging. The "X" designation is for use in specifications when lead finishes A, B, and C are considered acceptable and interchangeable without preference.

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1.3 Absolute maximum ratings. 1/ 2/

Supply voltage range to ground potential (V_{CC})	-0.5 V dc to +7.0 V dc
DC input voltage range (V_{IN})	-0.5 V dc to $V_{CC} + 5.0$ V dc
Voltage applied to three-state output (V_{IS})	-0.5 V dc to $V_{CC} + 5.0$ V dc
Thermal resistance, junction-to-case (θ_{JC})	See MIL-STD-1835
Thermal resistance, junction-to-ambient (θ_{JA})	+50°C/W
Power dissipation (P_D)	2.0 W
Junction temperature (T_J)	+150°C 3/
Lead temperature (soldering, 10 seconds)	+260°C
Storage temperature range	-65°C to +150°C

1.4 Recommended operating conditions.

Supply voltage relative to ground (V_{CC})	+4.5 V dc minimum to +5.5 V dc maximum
Input high voltage (V_{IH})	2.0 V dc to V_{CC}
Input low voltage (V_{IL})	0 V dc to 0.8 V dc
Maximum input signal transition time (t_{IN})	250 ns
Case operating temperature range (T_C)	-55°C to +125°C

1.5 Digital logic testing for device classes Q and V.

Fault coverage measurement of manufacturing logic tests (MIL-STD-883, test method 5012) 4/ percent

2. APPLICABLE DOCUMENTS.

2.1 Government specification, standards, bulletin, and handbook. Unless otherwise specified, the following specification, standards, bulletin, and handbook of the issue listed in that issue of the Department of Defense Index of Specifications and Standards specified in the solicitation, form a part of this drawing to the extent specified herein.

SPECIFICATION

MILITARY

MIL-I-38535 - Integrated Circuits, Manufacturing, General Specification for.

STANDARDS

MILITARY

MIL-STD-883 - Test Methods and Procedures for Microelectronics.
MIL-STD-973 - Configuration Management.
MIL-STD-1835 - Microcircuit Case Outlines.

BULLETIN

MILITARY

MIL-BUL-103 - List of Standardized Military Drawings (SMD's).

HANDBOOK

MILITARY

MIL-HDBK-780 - Standardized Military Drawings.

(Copies of the specifications, standards, bulletin, and handbook required by manufacturers in connection with specific acquisition functions should be obtained from the contracting activity or as directed by the contracting activity.)

- 1/ Stresses above the absolute maximum rating may cause permanent damage to the device. Extended operation at the maximum levels may degrade performance and affect reliability.
- 2/ All voltage values in this drawing are with respect to V_{SS} .
- 3/ Maximum junction temperature shall not be exceeded except for allowable short duration burn-in screening conditions in accordance with method 5004 of MIL-STD-883.
- 4/ Values will be added when they become available.

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2.2 Non-government publications. The following documents form a part of this document to the extent specified herein. Unless otherwise specified, the issues of the documents which are DoD adopted are those listed in the issue of the DODISS cited in the solicitation. Unless otherwise specified, the issues of documents not listed in the DODISS are the issues of the documents cited in the solicitation.

AMERICAN SOCIETY FOR TESTING AND MATERIALS (ASTM)

ASTM Standard F1192-88 - Standard guide for the measurement of single event phenomena from Heavy Ion Irradiation of Semiconductor Devices.

(Applications for copies of ASTM publications should be addressed to the American Society for Testing and Materials, 1916 Race Street, Philadelphia, PA 19103.)

ELECTRONIC INDUSTRIES ASSOCIATION (EIA)

JEDEC Standard No. 17 - A Standardized Test Procedure for the Characterization of Latch-up in CMOS Integrated Circuits.

(Applications for copies should be addressed to the Electronics Industries Association, 2001 Pennsylvania Street, N.W., Washington D.C. 20006.)

(Non-government standards and other publications are normally available from the organizations that prepare or distribute the documents. These documents also may be available in or through libraries or other informational services.)

2.3 Order of precedence. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing shall take precedence.

3. REQUIREMENTS

3.1 Item requirements. The individual item requirements for device class M shall be in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices" and as specified herein. The individual item requirements for device classes Q and V shall be in accordance with MIL-I-38535, the device manufacturer's Quality Management (QM) plan, and as specified herein.

3.2 Design, construction, and physical dimensions. The design, construction, and physical dimensions shall be as specified in MIL-STD-883 (see 3.1 herein) for device class M and MIL-I-38535 for device classes Q and V and herein.

3.2.1 Case outline. The case outline shall be in accordance with 1.2.4 herein and figure 1.

3.2.2 Terminal connections. The terminal connections shall be as specified on figure 2.

3.2.3 Radiation exposure circuit. The radiation exposure circuit will be provided when RHA product becomes available.

3.2.4 Logic block diagram. The logic block diagram shall be as specified on figure 2.

3.3 Electrical performance characteristics and postirradiation parameter limits. Unless otherwise specified herein, the electrical performance characteristics and postirradiation parameter limits are as specified in table I and shall apply over the full case operating temperature range.

3.4 Electrical test requirements. The electrical test requirements shall be the subgroups specified in table IIA. The electrical tests for each subgroup are defined in table I.

3.5 Marking. The part shall be marked with the PIN listed in 1.2 herein. Marking for device class M shall be in accordance with MIL-STD-883 (see 3.1 herein). In addition, the manufacturer's PIN may also be marked as listed in MIL-BUL-103. Marking for device classes Q and V shall be in accordance with MIL-I-38535.

3.5.1 Certification/compliance mark. The compliance mark for device class M shall be a "C" as required in MIL-STD-883 (see 3.1 herein). The certification mark for device classes Q and V shall be a "QML" or "Q" as required in MIL-I-38535.

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3.6 Certificate of compliance. For device class M, a certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in MIL-BUL-103 (see 6.7.2 herein). For device classes Q and V, a certificate of compliance shall be required from a QML-38535 listed manufacturer in order to supply to the requirements of this drawing (see 6.7.1 herein). The certificate of compliance submitted to DESC-EC prior to listing as an approved source of supply for this drawing shall affirm that the manufacturer's product meets, for device class M, the requirements of MIL-STD-883 (see 3.1 herein), or for device classes Q and V, the requirements of MIL-I-38535 and the requirements herein.

3.7 Certificate of conformance. A certificate of conformance as required for device class M in MIL-STD-883 (see 3.1 herein) or for device classes Q and V in MIL-I-38535 shall be provided with each lot of microcircuits delivered to this drawing.

3.8 Notification of change for device class M. For device class M, notification to DESC-EC of change of product (see 6.2 herein) involving devices acquired to this drawing is required for any change as defined in MIL-STD-973.

3.9 Verification and review for device class M. For device class M, DESC, DESC's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.

3.10 Microcircuit group assignment for device class M. Device class M devices covered by this drawing shall be in microcircuit group number 42 (see MIL-I-38535, appendix A).

4. QUALITY ASSURANCE PROVISIONS

4.1 Sampling and inspection. For device class M, sampling and inspection procedures shall be in accordance with MIL-STD-883 (see 3.1 herein). For device classes Q and V, sampling and inspection procedures shall be in accordance with MIL-I-38535 and the device manufacturer's QM plan.

4.2 Screening. For device class M, screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection. For device classes Q and V, screening shall be in accordance with MIL-I-38535, and shall be conducted on all devices prior to qualification and technology conformance inspection.

4.2.1 Additional criteria for device class M.

- a. Delete the sequence specified as initial (preburn-in) electrical parameters through interim (postburn-in) electrical parameters of method 5004 and substitute lines 1 through 6 of table IIA herein.
- b. For device class M, the test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. For device class M, the test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1015.
- c. Interim and final electrical parameters shall be as specified in table II herein.

4.2.2 Additional criteria for device classes Q and V.

- a. The burn-in test duration, test condition and test temperature, or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-I-38535. The burn-in test circuit shall be maintained under document revision level control of the device manufacturer's Technology Review Board (TRB) in accordance with MIL-I-38535 and shall be made available to the acquiring or preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1015.
- b. Interim and final electrical test parameters shall be as specified in table II herein.
- c. Additional screening for device class V beyond the requirements of device class Q shall be as specified in appendix B of MIL-I-38535.

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TABLE I. Electrical performance characteristics.

Test	Symbol	Conditions 4.5 V ≤ V _{CC} ≤ 5.5 V -55°C ≤ T _C ≤ +125°C unless otherwise specified	Group A subgroups	Device type	Limits		Unit
					Min	Max	
High level output voltage	V _{OH}	V _{CC} = 4.5 V, I _{OH} = -4.0 mA	1,2,3	ALL	2.4		V
Low level output voltage 1/	V _{OL}	V _{CC} = 5.5 V, I _{OL} = 4.0 mA,	1,2,3	ALL		0.4	V
Quiescent LCA supply current 2/	I _{CCO}	V _{CC} = V _{IN} = 5.5 V	1,2,3	ALL		50	mA
Input leakage current	I _{IL}	V _{IN} = 0 V and 5.5 V, V _{CC} = 5.5 V	1,2,3	ALL	-10	+10	μA
Pad pull-up current (when selected)	I _{RIN}	V _{IN} = 0 V	1,2,3	ALL		0.5	mA
Horizontal long line pull-up current (when selected)	I _{RLL}	At logic low	1,2,3	ALL		5.0	mA
Input capacitance	C _{IN}	See 4.4.1e	4,5,6	ALL		15	pF
Functional test	FT	See 4.4.1c	7,8A,8B	ALL			
Interconnect + t _{PID} + t _{OPS} + t _{ILO}	t _{B1}		9,10,11	01		321.5	ns
				02		199	
Interconnect + t _{PID} + t _{HHO} + t _{OPS}	t _{B2}		9,10,11	01		278.5	ns
				02		225.6	
Interconnect + t _{PID} + t _{OPS} + t _{IHO}	t _{B3}		9,10,11	01		417.5	ns
				02		247	
Interconnect + t _{PID} + t _{OPS} + t _{RIO}	t _{B4}		9,10,11	01		446.4	ns
				02		274	
Interconnect + t _{CKO} + t _{ICK} + t _{CKI}	t _{B5}		9,10,11	01		22.6	ns
				02		12.6	
Interconnect + t _{CKO} + t _{HHCK} + t _{CKHH}	t _{B6}		9,10,11	01		20.7	ns
				02		13.6	
Interconnect + t _{CKO} + t _{IHCK} + t _{CKIH}	t _{B7}		9,10,11	01		26.6	ns
				02		14.6	

See footnotes at end of table.

STANDARD
MICROCIRCUIT DRAWING
DEFENSE ELECTRONICS SUPPLY CENTER
DAYTON, OHIO 45444

SIZE
A

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SHEET

6

TABLE I. Electrical performance characteristics.

TABLE 1. Electrical performance characteristics.							
Test	Symbol	Conditions 4.5 V ≤ V _{CC} ≤ 5.5 V -55°C ≤ T _C ≤ +125°C unless otherwise specified	Group A subgroups	Device type	Limits		Unit
					Min	Max	
Interconnect + t _{CKO} + t _{DICK} + t _{CKDI}	t _{B8}		9,10,11	01		18.7	ns
				02		10.6	
Interconnect + t _{CKO} + t _{ECCK} + t _{CKEC}	t _{B9}		9,10,11	01		23.6	ns
				02		13.6	
Interconnect + t _{PID} + t _{OPS} + t _{OPCY} + t _{SUM} - t _{BYP}	t _{B10}		9,10,11	01		477.1	ns
				02		355.8	
Interconnect + t _{PID} + t _{OPS} + t _{ASCY} + t _{SUM} - t _{BYP}	t _{B11}		9,10,11	01		548	ns
				02		380.9	
Interconnect + t _{PID} + t _{OPS} + t _{INCY} + t _{SUM}	t _{B12}		9,10,11	01		271.7	ns
				02		207.3	
Interconnect + t _{PID} + t _{OPS} + t _{INCY} + t _{SUM} + t _{BYP}	t _{B13}		9,10,11	01		108.9	ns
				02		78.6	
WIDE DECODER SWITCHING CHARACTERISTICS							
Full length, both pull-ups inputs from IOB I-pins	T _{WAF}	See figures 3 and 4 as applicable. 3/	4/	ALL		15	ns
Full length, both pull-ups inputs from internal logic	T _{WAFL}		4/	ALL		18	ns
Half length, one pull-up inputs from IOB I-pins	T _{WAO}		4/	ALL		15	ns
Half length, one pull-up inputs from internal logic	T _{WAOL}		4/	ALL		18	ns
CLB SWITCHING CHARACTERISTICS							
Combinatorial delay F/G inputs to X/Y outputs	T _{ILO}	See figures 3 and 4, as applicable.	5/	01		10	ns
				02		6	
Combinatorial delay F/G inputs via H' to X/Y outputs	T _{IHO}		5/	01		14	ns
				02		8	
Combinatorial delay C inputs via H' to X/Y outputs	T _{HHO}		5/	01		8	ns
				02		7	

See footnotes at end of table.

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TABLE I. Electrical performance characteristics - continued.

Test	Symbol	Conditions 4.5 V ≤ V _{CC} ≤ 5.5 V -55°C ≤ T _C ≤ +125°C unless otherwise specified	Group A subgroups	Device type	Limits		Unit
					Min	Max	
CLB SWITCHING CHARACTERISTICS - Continued.							
CLB fast carry logic operand inputs (F1,F2,G1, G4) to C _{OUT}	T _{OPCY}	See figures 3 and 4, as applicable	<u>6/</u>	01		8	ns
				02		7	
CLB fast carry logic add/ subtract input (F3) to C _{OUT}	T _{ASCY}		<u>6/</u>	01		11	ns
				02		8	
CLB fast carry logic initialization inputs (F1,F3) to C _{OUT}	T _{INCY}		<u>6/</u>	ALL		6	ns
CLB fast carry logic C _{IN} through function generators to X/Y outputs	T _{SUM}		<u>6/</u>	01		12	ns
				02		8	
CLB fast carry logic C _{IN} to C _{OUT} , bypass function generators	T _{BYP}		<u>6/</u>	01		3	ns
				02		2	
Sequential delays clock K to outputs Q	T _{CKO}		<u>5/</u>	01		9	ns
				02		5	
Set-up time before clock K, F/G inputs	T _{ICK}		<u>5/</u>	01	11		ns
				02	6		
Set-up time before clock K, F/G inputs via H'	T _{IHCK}		<u>5/</u>	01	15		ns
				02	8		
Set-up time before clock K, C inputs via H1	T _{HHCK}		<u>5/</u>	01	9		ns
		02		7			
Set-up time before clock K, C inputs via DIN	T _{DICK}	<u>5/</u>	01	7		ns	
			02	4			
Set-up time before clock K, C inputs via EC	T _{ECCK}	<u>5/</u>	01	12		ns	
			02	7			

See footnotes at end of table.

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TABLE I. Electrical performance characteristics - continued.

Test	Symbol	Conditions 4.5 V ≤ V _{CC} ≤ 5.5 V -55°C ≤ T _C ≤ +125°C unless otherwise specified	Group A subgroups	Device type	Limits		Unit
					Min	Max	
CLB SWITCHING CHARACTERISTICS - Continued.							
Set-up time before clock K, C inputs via S/R, going low (inactive)	T _{RCK}	See figures 3 and 4, as applicable	<u>4/</u>	01	10		ns
				02	6		
Set-up time before clock K, C _{IN} input via F ^T /G'	T _{CCK}		<u>4/</u>	ALL	8		ns
Set-up time before clock K, C _{IN} input via F ^T /G' and H'	T _{CHCK}		<u>4/</u>	ALL	10		ns
Hold time after clock K, F/G inputs	T _{CKI}		<u>5/</u>	ALL	0		ns
Hold time after clock K, F/G inputs via H'	T _{CKIH}		<u>5/</u>	ALL	0		ns
Hold time after clock K, C inputs via H1	T _{CKHH}		<u>5/</u>	ALL	0		ns
Hold time after clock K, C inputs via DIN	T _{CKDI}		<u>5/</u>	ALL	0		ns
Hold time after clock K, C inputs via EC	T _{CKEC}		<u>5/</u>	ALL	0		ns
Hold time after clock K, C inputs via S/R, going low (inactive)	T _{CKR}		<u>4/</u>	ALL	0		ns
Clock high time	T _{CH}		<u>4/</u>	01	5.5		ns
				02	5		
Clock low time	T _{CL}		<u>4/</u>	01	5.5		ns
				02	5		
Set/Reset direct width (high)	T _{RPW}		<u>4/</u>	01	6		ns
				02	5		

See footnotes at end of table.

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TABLE I. Electrical performance characteristics - continued.

Test	Symbol	Conditions 4.5 V ≤ V _{CC} ≤ 5.5 V -55°C ≤ T _C ≤ +125°C unless otherwise specified	Group A subgroups	Device type	Limits		Unit	
					Min	Max		
CLB SWITCHING CHARACTERISTICS - continued.								
Set/Reset direct delay, from C to Q	T _{RIO}	See figures 3 and 4, as applicable.	<u>5/</u>	01		15	ns	
				02		9		
Master set/reset width (high or low)	T _{MRW}		<u>4/</u>	01	120		ns	
				02	110			
Master set/reset delay from global set/reset net to Q	T _{MRQ}		<u>4/</u>	01		130	ns	
				02		120		
CLB SWITCHING CHARACTERISTICS (RAM OPTION)								
Read operation, address read cycle time (16 X 2)	T _{RC}		See figures 3 and 4, as applicable. <u>7/</u>	<u>8/</u>	01	12		ns
					02	7		
Read operation, address read cycle time (32 X 1)	T _{RCT}	<u>8/</u>		01	15		ns	
				02	10			
Read operation data valid after address change (no write enable) (16 X 2)	T _{ILO}	<u>8/</u>		01		10	ns	
				02		6		
Read operation data valid after address change (no write enable) (32 X 1)	T _{IHO}	<u>8/</u>		01		14	ns	
				02		8		
Read during write, clocking data into flip flop address setup time before clock K (16 X 2)	T _{ICK}	<u>8/</u>		01	11		ns	
				02	6			
Read during write, clocking data into flip flop address setup time before clock K (32 X 1)	T _{IHCK}	<u>8/</u>		01	15		ns	
				02	8			

See footnotes at end of table.

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TABLE I. Electrical performance characteristics - continued.

Test	Symbol	Conditions 4.5 V ≤ V _{CC} ≤ 5.5 V -55°C ≤ T _C ≤ +125°C unless otherwise specified	Group A subgroups	Device type	Limits		Unit
					Min	Max	
CLB SWITCHING CHARACTERISTICS (RAM OPTION) - Continued.							
Read during write, data valid after WE going active (16 X 2)	T _{WO}	See figures 3 and 4, as applicable 7/	8/	01		15	ns
				02		12	
Read during write, (DIN stable before WE) (32 X 1)	T _{WOT}		8/	01		27	ns
				02		15	
Read during write, data valid after DIN (16 X 2)	T _{DO}		8/	01		19	ns
				02		11	
Read during write, (DIN change during WE) (32 X 1)	T _{DOT}		8/	01		22	ns
				02		14	
Read during write, clocking data into flip flop, WE setup time before clock K (16 X 2)	T _{WCK}		8/	01	15		ns
				02	12		
Read during write, clocking data into flip flop, WE setup time before clock K (32 X 1)	T _{WCKT}		8/	01	27		ns
				02	15		
Read during write, clocking data into flip flop, data setup time before clock K (16 X 2)	T _{DCK}		8/	01	19		ns
				02	11		
Read during write, clocking data into flip flop, data setup time before clock K (32 X 1)	T _{DCKT}		8/	01	22		ns
				02	14		
Write operation, address write cycle time (16 X 2)	T _{WC}		8/	01	16		ns
				02	9		

See footnotes at end of table.

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TABLE I. Electrical Performance Characteristics - continued.

Test	Symbol	Conditions 4.5 V ≤ V _{CC} ≤ 5.5 V -55°C ≤ T _C ≤ +125°C unless otherwise specified	Group A subgroups	Device type	Limits		Unit
					Min	Max	
CLB SWITCHING CHARACTERISTICS (RAM OPTION) - Continued.							
Write operation, address write cycle time (32 X 1)	T _{WCT}	See figure 3 and 4, as applicable 7/	8/	01	16		ns
				02	9		
Write operation, write enable pulse width (high) (16 X 2)	T _{WP}		8/	01	12		ns
				02	5		
Write operation, write enable pulse width (high) (32 X 1)	T _{WPT}		8/	01	12		ns
				02	5		
Write operation, address setup time before beginning of WE (16 X 2)	T _{AS}		8/	ALL	2		ns
Write operation, address setup time before beginning of WE (32 X 1)	T _{AST}		8/	ALL	2		ns
Write operation, address hold time after end of WE (16 X 2)	T _{AH}		8/	ALL	2		ns
Write operation, address hold time after end of WE (32 X 1)	T _{AHT}		8/	ALL	2		ns
Write operation, DIN setup time before end of WE (16 X 2)	T _{DS}		8/	ALL	4		ns
Write operation, DIN setup time before end of WE (32 X 1)	T _{DST}		8/	ALL	5		ns
Write operation, DIN hold time after end of WE	T _{DHT}		8/	ALL	2		ns

See footnotes at end of table.

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TABLE I. Electrical Performance Characteristics - continued.

Test	Symbol	Conditions 4.5 V ≤ V _{CC} ≤ 5.5 V -55°C ≤ T _C ≤ +125°C unless otherwise specified	Group A subgroups	Device type	Limits		Unit
					Min	Max	
IOB SWITCHING CHARACTERISTICS							
Input propagation delay, pad to I1, I2	T _{PID}	See figures 3 and 4 as applicable. 9/ 10/	5/	ALL		4	ns
Input propagation delay, pad to I1, I2, via transparent latch (fast)	T _{PLI}		4/	01		13	ns
				02		8	
Input propagation delay, pad to I1, I2, via transparent latch (with delay)	T _{PDLI}		4/	01		30	ns
				02		26	
Input propagation delay, clock (IK) to I1, I2, (flip-flop)	T _{IKRI}		4/	01		8.5	ns
		02			8		
Input propagation delay, clock (IK) to I1, I2, (latch enable)	T _{IKLI}	4/	01		9	ns	
			02		8		
Setup time, pad to clock (IK), fast	T _{PICK}	See figures 3 and 4 as applicable. 9/ 10/ 11/	4/	01	9		ns
				02	7		
Setup time, pad to clock (IK), with delay	T _{PICKD}		4/	01	35		ns
				02	25		
Hold time, pad to clock (IK), fast	T _{IKPI}		4/	ALL		1	ns
Hold time, pad to clock (IK), with delay	T _{IKPID}		4/	ALL		negative	ns
Output propagation delay clock (OK) to pad, (fast)	T _{OKPOF}	See figures 3 and 4 as applicable. 9/ 10/	4/	01		11	ns
				02		7.5	
Output propagation delay clock (OK) to pad, (slew rate limited)	T _{OKPOS}		4/	01		16	ns
				02		11.5	
Output propagation delay output (O) to pad (fast)	T _{OPF}		4/	01		10	ns
				02		9	

See footnotes at end of table.

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TABLE I. Electrical Performance Characteristics - continued.

Test	Symbol	Conditions 4.5 V ≤ V _{CC} ≤ 5.5 V -55°C ≤ T _C ≤ +125°C unless otherwise specified	Group A subgroups	Device type	Limits		Unit
					Min	Max	
IOB SWITCHING CHARACTERISTICS - continued							
Output propagation delay output (0) to pad (slew rate limited)	T _{OPS}	See figures 3 and 4 as applicable. 9/ 10/	5/	01		15	ns
				02		13	
Output propagation delay 3-state to pad begin hi-Z (fast)	T _{TSHZF}		4/	01		10	ns
				02		9	
Output propagation delay 3-state to pad active and valid (fast)	T _{TSO NF}		4/	01		15	ns
				02		13	
Output propagation delay 3-state to pad active and valid (slew rate limited)	T _{TSO NS}		4/	01		20	ns
				02		17	
Setup time, output (0) to clock (OK)	T _{OOK}		4/	01	13		ns
				02	8		
Hold time, output (0) to clock (OK)	T _{OKO}		4/	ALL		0	ns
Clock high or low time	T _{CH} / T _{CL}		4/	01	6		ns
				02	5		
Global set/reset delay from GSR net through Q to I1, I2	T _{RRI}		4/	01		20	ns
				02		14.5	
Global set/reset delay from GSR net to pad	T _{RPO}		4/	01		23	ns
				02		18	
Global set/reset GSR width	T _{MRW}		4/	ALL	21		ns

See footnotes at end of table.

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TABLE I. Electrical Performance Characteristics - continued.

- 1/ With 50 percent of the outputs simultaneously sinking 4 mA.
- 2/ With no output current loads, no active input or long line pull-resistors, all package pins at V_{CC} or GND, and the LCA configured with a MakeBits "tie" option.
- 3/ These delays are specified from the decoder input to the decoder output. For pad-to-pad delays, add the input delay (T_{PID}) and output delay (T_{OPF} or T_{OPS}).
- 4/ Parameter is not tested but is guaranteed by characterization data which is taken at initial device introduction, prior to the introduction of significant changes, and at least twice yearly.
- 5/ Parameter is not directly tested. Devices are first 100 percent functionality tested. Benchmark patterns (t_{B1} - t_{B13}) are then used to determine the compliance of this parameter. Characterization data is taken at initial device introduction, prior to the introduction of significant changes, and at least twice yearly to monitor correlation between benchmark patterns and this parameter.
- 6/ Benchmark patterns (t_{B1} - t_{B13}) are used to determine compliance to this parameter.
- 7/ Timing for the 16 X 1 RAM option is identical to 16 X 2 RAM timing.
- 8/ Values indicated are guaranteed by characterization data if application note, provided by manufacturer, is followed. If application note is not followed, indicated values are typical only.
- 9/ Timing is measured at pin threshold, with 50 pF external capacitive loads including test fixture. Slew rate limited output rise/fall times are approximately two times longer than fast output rise/fall times. A maximum total external capacitive load for simultaneous fast mode switching in the same direction is 200 pF per power/ground pin pair. For slew rate limited outputs this total is two times larger. Exceeding this maximum capacitive load can result in ground bounce of greater than 1.5 V amplitude, less than 5 ns duration, which might cause problems when the LCA drives clocks and other asynchronous signals.
- 10/ Voltage levels of unused (bonded and unbonded) pads must be valid logic levels. Each can be configured with the internal pull-up or pull-down resistor or alternatively configured as a driven output or be driven from an external source.
- 11/ Input pad setup times and hold times are specified with respect to the internal clock (IK). To calculate system setup time, subtract clock delay (clock pad to IK) from the specified input pad setup time value, but do not subtract below zero. "Negative" hold time means that the delay in the input data is adequate for the external system hold time to be zero, provided the input clock uses the global signal distribution from pad to IK.

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Technical drawing of a ceramic tie-bar assembly, showing top, bottom, and detail views.

TOP VIEW:

- Central square: .050 DIA. PIN 1 INDEX
- Dimensions: 1.550 ± .016 SQ., 1.920 ± .020 4 PLACES
- Part numbers: 172, 171, 228, 1, 115, 114, 57, 58
- Labels: CERAMIC TIE-BAR 4 PLS, .008 ± .002 228 PLACES, .025 224 PLACES (LEAD PITCH), TOP MARK SEE NOTE 3

DETAIL A:

- Dimensions: .130 TYP., .020 REF., .050 TYP., .075 REF., .075 TYP., .0125 REF., .0125 REF.

BOTTOM VIEW:

- Central square: .075 REF. (4 PLS), .900 SQ. MAX.
- Dimensions: 2.500 ± .030 2 PLS, 2.300 (12 PLCS.)
- Part numbers: 115, 114, 58, 57, 171, 172, 228
- Labels: REF. .040 X 45°, REF. .020 X 45°

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Case Y - Continued

Inches	mm	Inches	mm
.002	0.05	.035	0.89
.004	0.10	.040	1.02
.005	0.13	.043	1.09
.008	0.20	.050	1.27
.009	0.23	.075	1.91
.0125	0.32	.090	2.29
.016	0.41	.130	3.30
.0175	0.445	.900	22.86
.020	0.51	1.550	39.37
.021	0.53	1.920	48.77
.025	0.64	2.300	58.42
.030	0.76	2.500	63.50

NOTES:

1. Dimensions are in inches.
2. The US government preferred system of measurement is the metric SI system. However, this item was originally designed using inch-pound units of measurement. In the event of conflict between the metric and inch-pound units, the inch-pound units shall take precedence.
3. Top side mark location, product mark is located on the nonlid side of package; i.e., lid side facing down. When mounted in this position, the pin out is clockwise.
4. The leads of this package style shall be protected from mechanical distortion and damage such that dimensions pertaining to relative lead/body "true positions" and lead "coplanarity" are always maintained until the next higher level package attachment process is complete. Package lead protection mechanisms (tie bars) are shown on the drawing for reference only. When microcircuit devices contained in this package style are shipped for use in Government equipment, or shipped directly to the Government as spare parts or mechanical qualification samples, lead "true position" and "coplanarity" protection shall be in place.

FIGURE 1. Case outline - Continued.

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Case 2

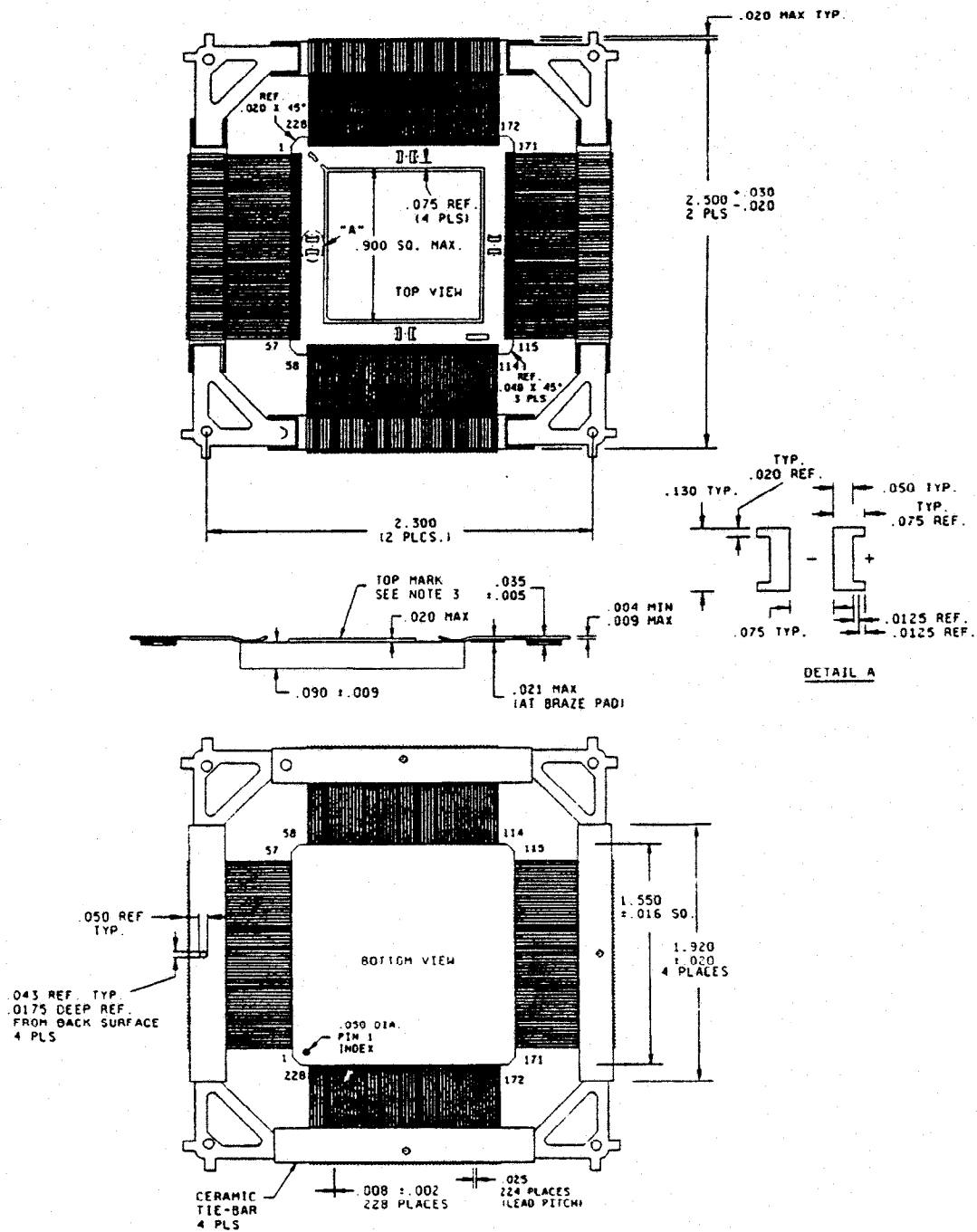


FIGURE 1. Case outline - Continued.

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Case Z - Continued

Inches	mm	Inches	mm
.002	0.05	.035	0.89
.004	0.10	.040	1.02
.005	0.13	.043	1.09
.008	0.20	.050	1.27
.009	0.23	.075	1.91
.0125	0.32	.090	2.29
.016	0.41	.130	3.30
.0175	0.445	.900	22.86
.020	0.51	1.550	39.37
.021	0.53	1.920	48.77
.025	0.64	2.300	58.42
.030	0.76	2.500	63.50

NOTES:

1. Dimensions are in inches.
2. The US government preferred system of measurement is the metric SI system. However, this item was originally designed using inch-pound units of measurement. In the event of conflict between the metric and inch-pound units, the inch-pound units shall take precedence.
3. Top side mark location, product mark is located on the lided side of package; i.e., lid side facing up. When mounted in this position, the pin out is counterclockwise.
4. The leads of this package style shall be protected from mechanical distortion and damage such that dimensions pertaining to relative lead/body "true positions" and lead "coplanarity" are always maintained until the next higher level package attachment process is complete. Package lead protection mechanisms (tie bars) are shown on the drawing for reference only. When microcircuit devices contained in this package style are shipped for use in Government equipment, or shipped directly to the Government as spare parts or mechanical qualification samples, lead "true position" and "coplanarity" protection shall be in place.

FIGURE 1. Case outline - Continued.

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Case outline X

Device type	ALL		Device type	ALL		Device type	ALL
Terminal number	Terminal symbol		Terminal number	Terminal symbol		Terminal number	Terminal symbol
A2	I/O (TDI)		C4	I/O (A17)		E16	I/O (HDC)
A3	I/O		C5	I/O		E17	I/O (LDC)
A4	I/O		C6	I/O		E18	I/O
A5	I/O		C7	GND		F1	I/O
A6	I/O		C8	I/O		F2	I/O
A7	I/O		C9	I/O		F3	I/O (A12)
A8	I/O		C10	I/O		F4	I/O
A9	I/O		C11	I/O		F15	I/O
A10	I/O		C12	GND		F16	I/O
A11	I/O		C13	I/O		F17	I/O
A12	I/O		C14	I/O		F18	I/O
A13	I/O		C15	M1		G1	I/O (A10)
A14	I/O		C16	M2		G2	I/O (A11)
A15	I/O		C17	I/O		G3	GND
A16	I/O		C18	I/O		G4	I/O
A17	I/O		D1	I/O		G15	I/O
A18	MO		D2	I/O (A13)		G16	GND
B1	I/O		D3	V _{CC}		G17	I/O
B2	SGCK1 (A15, I/O)		D4	GND		G18	I/O
B3	I/O		D5	I/O		H1	I/O
B4	I/O (TCK)		D6	I/O		H2	I/O
B5	I/O		D7	I/O		H3	I/O
B6	I/O		D8	I/O		H4	I/O
B7	I/O (TMS)		D9	GND		H15	I/O
B8	I/O		D10	V _{CC}		H16	I/O
B9	I/O		D11	I/O		H17	I/O
B10	I/O		D12	I/O		H18	I/O
B11	I/O		D13	I/O		J1	I/O
B12	I/O		D14	I/O		J2	I/O (A9)
B13	I/O		D15	GND		J3	I/O (A8)
B14	I/O		D16	V _{CC}		J4	V _{CC}
B15	I/O		D17	I/O		J15	V _{CC}
B16	SGCK2 (I/O)		D18	I/O		J16	I/O ($\overline{\text{ERR}}$, $\overline{\text{INIT}}$)
B17	PGCK2 (I/O)		E1	I/O		J17	I/O
B18	I/O		E2	I/O		J18	I/O
C1	I/O		E3	I/O			
C2	I/O (A14)		E4	I/O			
C3	PGCK1 (A16, I/O)		E15	I/O			

FIGURE 2. Terminal connections.

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Case outline X

Device type	ALL		Device type	ALL		Device type	ALL
Terminal number	Terminal symbol		Terminal number	Terminal symbol		Terminal number	Terminal symbol
K1	I/O		P18	I/O		U3	I/O (DO, DIN)
K2	I/O (A6)		R1	I/O		U4	I/O
K3	I/O (A7)		R2	I/O		U5	I/O
K4	GND		R3	GND		U6	I/O
K15	I/O		R4	V _{CC}		U7	I/O
K16	I/O		R5	I/O		U8	I/O
K17	I/O		R6	I/O			
K18	I/O		R7	I/O		U9	I/O (RS)
L1	I/O		R8	I/O		U10	I/O (D4)
L2	I/O		R9	GND		U11	I/O
L3	I/O		R10	V _{CC}		U12	I/O (D5)
L4	I/O		R11	I/O		U13	I/O
L15	I/O		R12	I/O		U14	I/O
L16	I/O		R13	I/O		U15	I/O
L17	I/O		R14	I/O		U16	PGCK3 (I/O)
L18	I/O		R15	V _{CC}		U17	DONE
M1	I/O (A5)		R16	GND		U18	I/O
M2	I/O (A4)		R17	I/O		V1	CCLK
M3	GND		R18	I/O			
M4	I/O		T1	I/O		V2	I/O (RCLK-BUSY/RDY)
M15	I/O		T2	I/O (CS1, A2)		V3	I/O (D1)
M16	GND					V4	I/O
M17	I/O		T3	I/O (AO, WS)		V5	I/O
M18	I/O		T4	SGCK4 (DOUT, I/O)		V6	I/O
N1	I/O		T5	I/O		V7	I/O (D2)
N2	I/O		T6	I/O		V8	I/O
N3	I/O (A3)		T7	GND		V9	I/O
N4	I/O		T8	I/O		V10	I/O
N15	I/O		T9	I/O (D3)		V11	I/O
N16	I/O		T10	I/O			
N17	I/O		T11	I/O		V12	I/O (CS0)
N18	I/O		T12	GND		V13	I/O
P1	I/O		T13	I/O		V14	I/O
P2	I/O		T14	I/O		V15	I/O
P3	I/O		T15	I/O (D7)		V16	I/O
P4	I/O		T16	SGCK3 (I/O)		V17	I/O (D6)
P15	I/O		T17	I/O			
P16	I/O		T18	I/O		V18	PROG
P17	I/O		U1	PGCK4 (I/O, A1)			
			U2	TDO			

FIGURE 2. Terminal connections - Continued.

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Case outline Y and Z

Device type	All	Device type	All	Device type	All
Terminal number	Terminal symbol	Terminal number	Terminal symbol	Terminal number	Terminal symbol
1	VSS	45	I/O	89	I/O
2	BUFGP_TL_A16_	46	I/O	90	I/O
	PGCK1_I/O	47	I/O	91	I/O
3	A17IO	48	I/O	92	I/O
4	I/O	49	I/O	93	I/O
5	I/O	50	I/O	94	I/O
6	TDI_I/O	51	I/O	95	VCC
7	TCK_I/O	52	I/O	96	I/O
8	I/O	53	I/O	97	I/O
9	I/O	54	BUFGS_BL_SGCK2	98	I/O
10	I/O		I/O	99	I/O
11	I/O	55	M1	100	VSS
12	I/O	56	VSS	101	I/O
13	I/O	57	M0	102	I/O
14	VSS	58	VCC	103	I/O
15	I/O	59	M2	104	I/O
16	I/O	60	BUFGS_BL_PGCK2	105	I/O
17	TMS_I/O		I/O	106	I/O
18	I/O	61	HDC_I/O	107	I/O
VCC 1/	VCC_BUS	62	I/O	108	I/O
19	I/O	63	I/O	109	I/O
20	I/O	64	I/O	110	I/O
21	I/O	65	LDC_I/O	111	I/O
22	I/O	66	I/O	112	BUFGS_BR_SGCK3_
23	I/O	67	I/O		I/O
24	I/O	68	I/O	113	VSS
25	I/O	69	I/O	114	DONE
26	I/O	70	I/O	115	VCC
27	VSS	71	I/O	116	/PROG
28	VCC	72	VSS	117	D7_I/O
29	I/O	73	I/O	118	BUFGP_BR_PGCK3_
30	I/O	74	I/O		I/O
31	I/O	75	I/O	119	I/O
32	I/O	76	I/O	120	I/O
33	I/O	VCC 1/	VCC-BUS	121	I/O
34	I/O	77	I/O	122	I/O
35	I/O	78	I/O	123	D6_I/O
36	I/O	79	I/O	124	I/O
37	VCC	80	I/O	125	I/O
38	I/O	81	I/O	126	I/O
39	I/O	82	I/O	127	I/O
40	I/O	83	I/O	128	I/O
41	I/O	84	/ERR_INIT_I/O	129	VSS
42	VSS	85	VCC	130	I/O
43	I/O	86	VSS	131	I/O
44	I/O	87	I/O	132	I/O
45	I/O	88	I/O	133	I/O

FIGURE 2. Terminal connections - Continued.

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Case outline Y and Z - Continued.

Device type	All	Device type	All	Device type	All
Terminal number	Terminal symbol	Terminal number	Terminal symbol	Terminal number	Terminal symbol
VCC	VCC-BUS	176	I/O	223	I/O
134	D5_I/O	177	I/O	224	I/O
135	/CS0_I/O	178	CS1_A2_I/O	225	I/O
136	I/O	179	A3_I/O	226	A14_I/O
137	I/O	180	I/O	227	BUFGS_TL_SGCK1_
138	I/O	181	I/O	228	A15_I/O
139	I/O	182	I/O		VCC
140	D4_I/O	183	I/O		
141	I/O	184	I/O		
142	VCC	185	I/O		
143	VSS	186	VSS		
144	D3_I/O	187	I/O		
145	/RS_I/O	188	I/O		
146	I/O	189	I/O		
147	I/O	190	I/O		
148	I/O	191	VCC		
149	I/O	192	A4_I/O		
150	D2_I/O	193	A5_I/O		
151	I/O	194	I/O		
152	VCC	195	I/O		
153	I/O	196	I/O		
154	I/O	197	I/O		
155	I/O	198	A6_I/O		
156	I/O	199	A7_I/O		
157	VSS	200	VSS		
158	I/O	201	VCC		
159	I/O	202	A8_I/O		
160	I/O	203	A9_I/O		
161	I/O	204	I/O		
162	I/O	205	I/O		
163	I/O	206	I/O		
164	D1_I/O	207	I/O		
165	BUSY_/RDY_	208	A10_I/O		
	RCLK_I/O	209	A11_I/O		
166	I/O	210	VCC		
167	I/O	211	I/O		
168	DO_DIN_I/O	212	I/O		
169	BUFGS_TR	213	I/O		
	SGCK4_DOUT_	214	I/O		
	I/O	215	VSS		
170	CCLK	216	I/O		
171	VCC	217	I/O		
172	TDO	218	I/O		
173	VSS	219	I/O		
174	A0_/WS_I/O	220	A12_I/O		
175	BUFGP_TR	221	A13_I/O		
	PGCK4_A1_I/O	222	I/O		

FIGURE 2. Terminal connections - Continued.

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I/O BLOCK

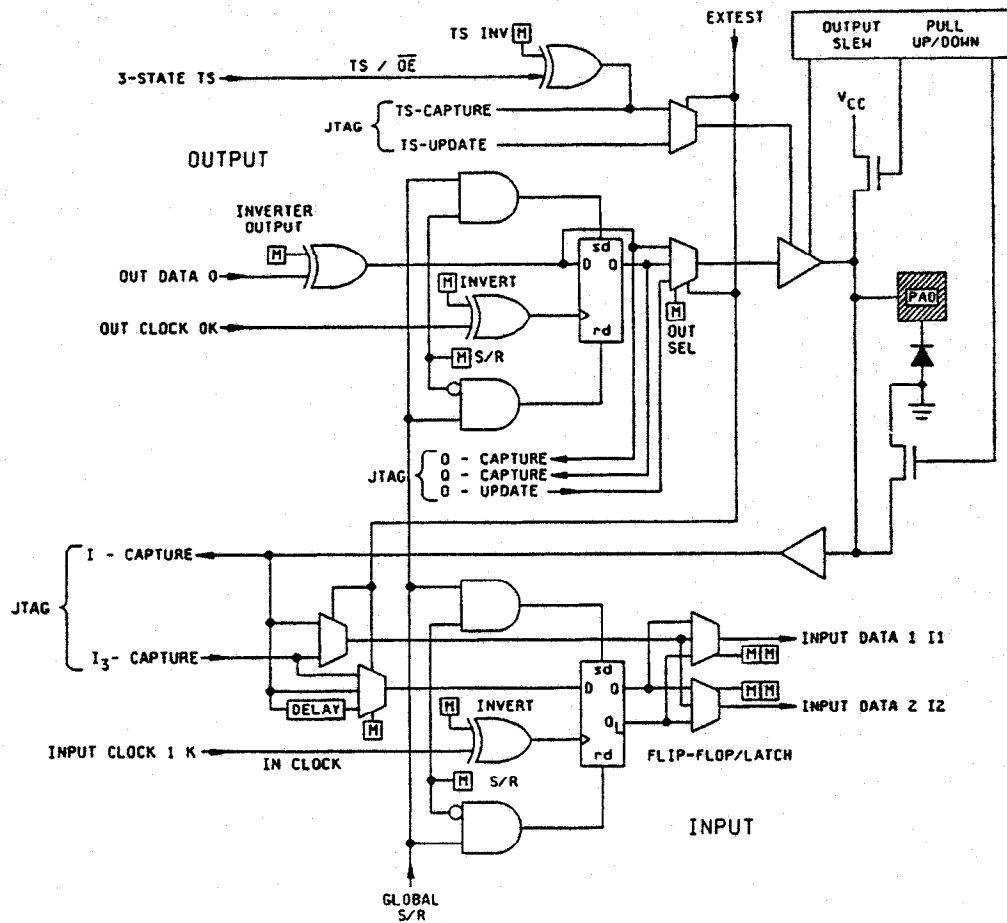


FIGURE 3. Logic block diagrams.

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CONFIGURABLE LOGIC BLOCK (CLB)

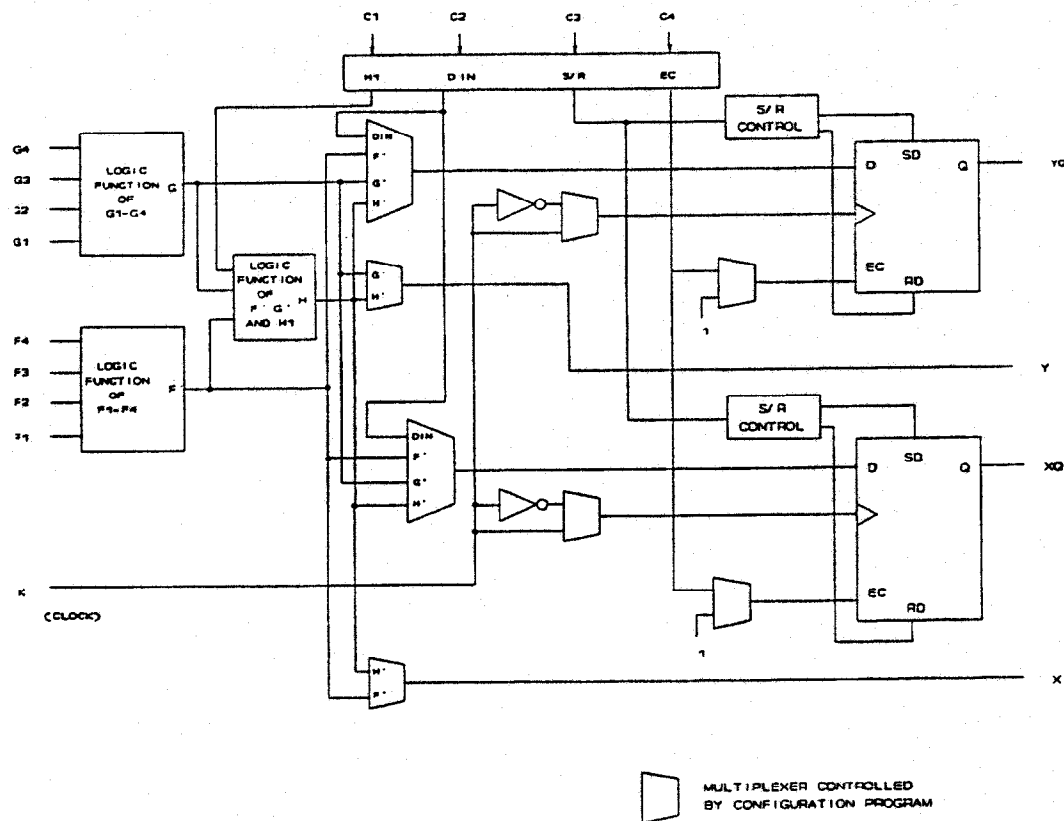


FIGURE 3. Logic block diagrams - Continued.

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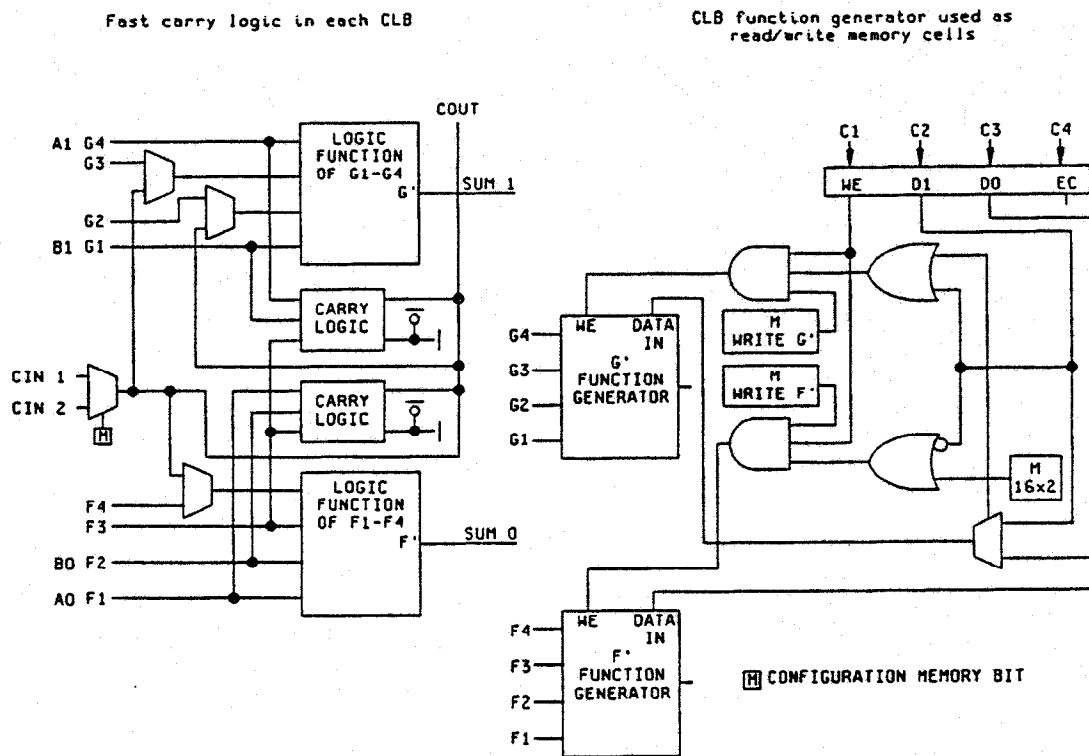


FIGURE 3. Logic block diagrams - Continued.

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BOUNDARY SCAN LOGIC

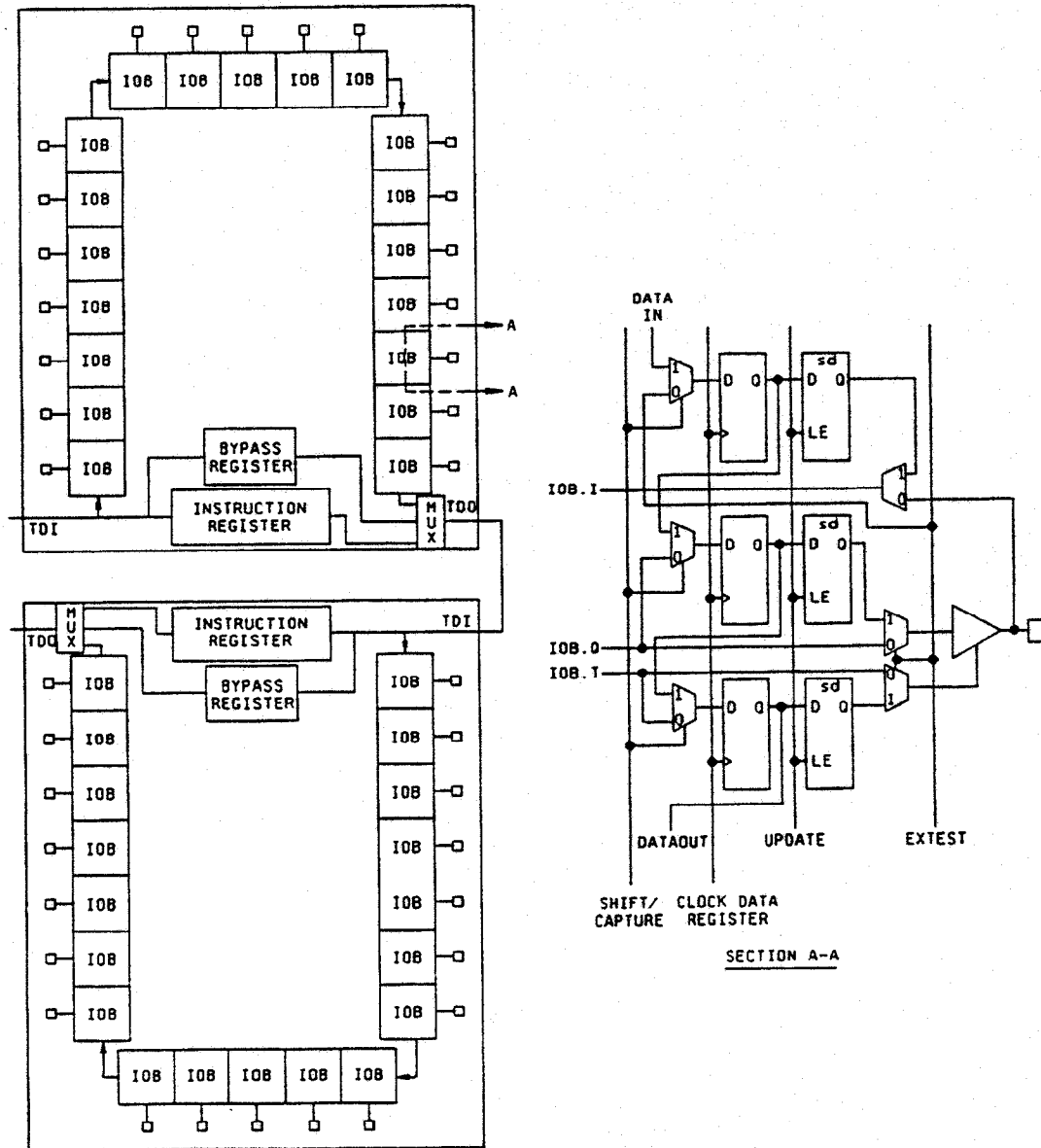


FIGURE 3. Logic block diagrams - Continued.

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GENERAL LOGIC CELL ARRAY (LCA) SWITCHING CHARACTERISTICS

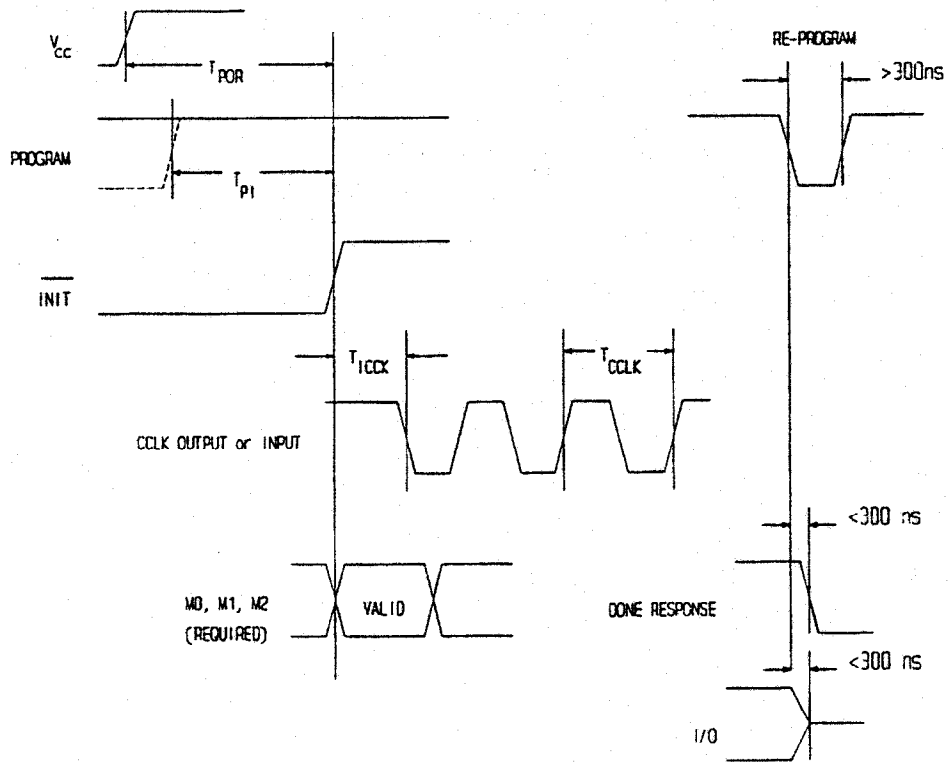


FIGURE 4. Timing diagrams and switching characteristics.

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CONFIGURABLE LOGIC BLOCK (CLB) SWITCHING CHARACTERISTICS

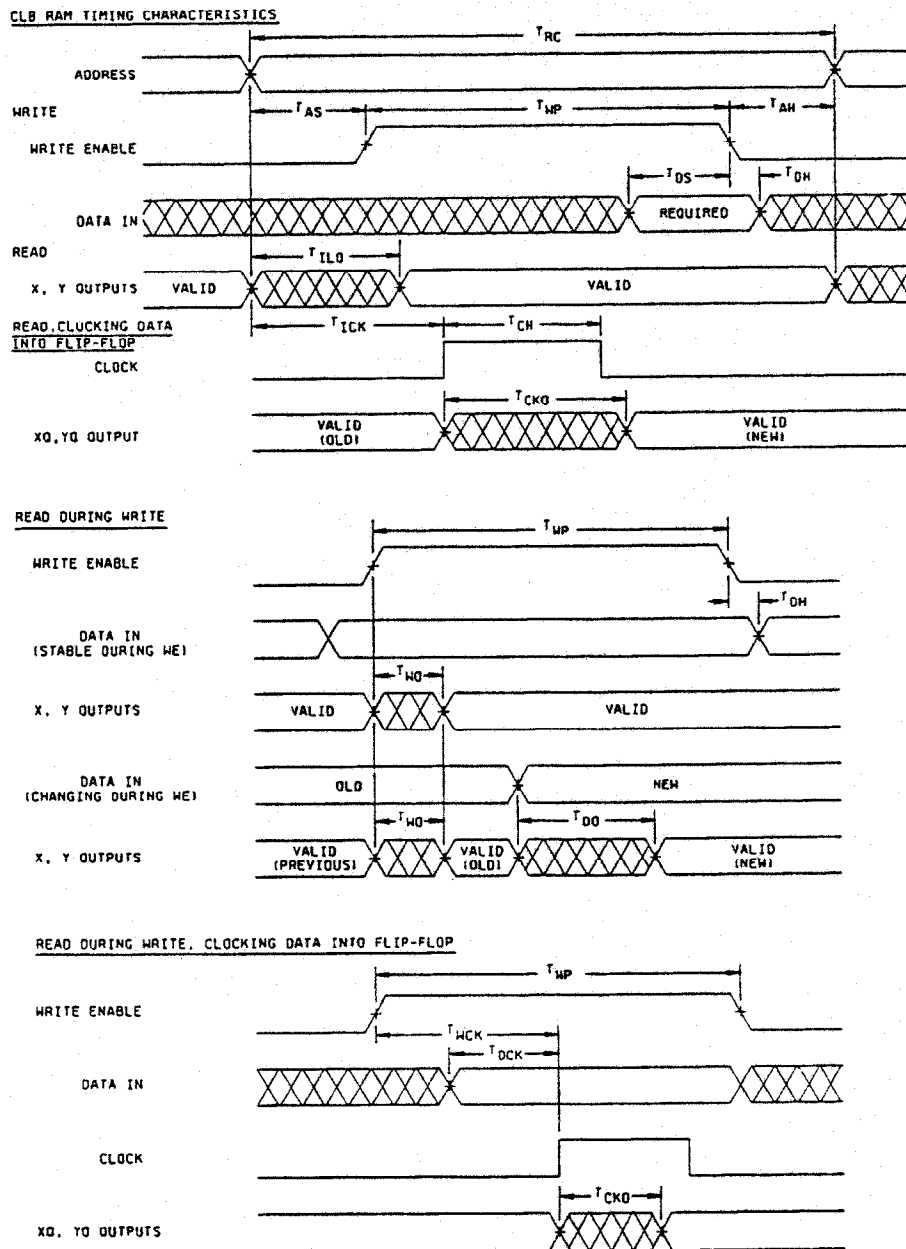


FIGURE 4. Timing diagrams and switching characteristics - Continued.

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I/O BLOCK (IOB) SWITCHING CHARACTERISTICS

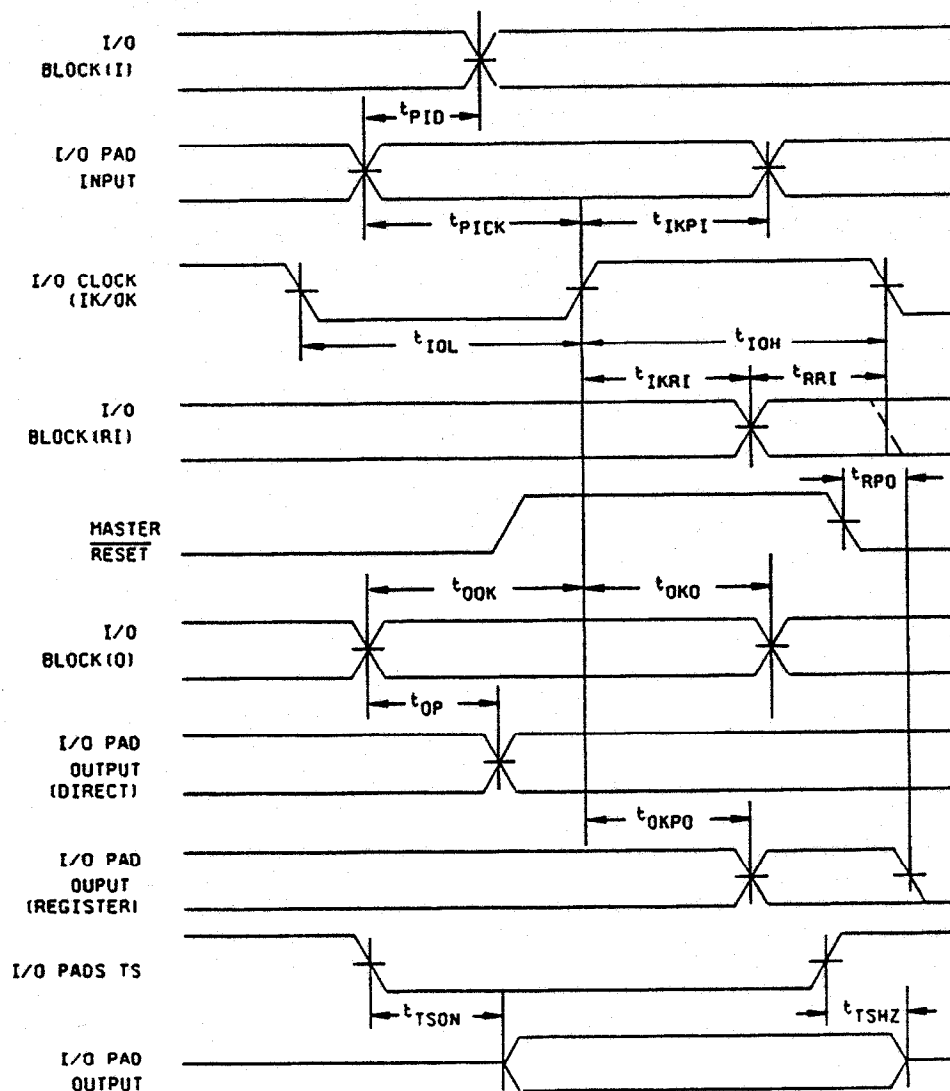


FIGURE 4. Timing diagrams and switching characteristics - Continued.

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4.3 Qualification inspection for device classes Q and V. Qualification inspection for device class Q shall be in accordance with MIL-I-38535. Inspections to be performed shall be those specified in MIL-I-38535 and herein for groups A, B, C, D, and E inspections (see 4.4.1 through 4.4.4).

4.4 Conformance inspection. Quality conformance inspection for device class M shall be in accordance with MIL-STD-883 (see 3.1 herein) and as specified herein. Inspections to be performed for device class M shall be those specified in method 5005 of MIL-STD-883 and herein for groups A, B, C, D, and E inspections (see 4.4.1 through 4.4.4). Technology conformance inspection for classes Q and V shall be in accordance with MIL-I-38535 including groups A, B, C, D, and E inspections and as specified herein except where option 2 of MIL-I-38535 permits alternate in-line control testing.

4.4.1 Group A inspection.

- a. Tests shall be as specified in table IIA herein.
- b. Subgroups 4, 5, and 6 (C_{IN} measurements) shall be measured only for the initial test and after process or design changes which may affect input capacitance.
- c. For device class M, subgroups 7, 8A, and 8B tests shall include verifying the functionality of the device. For device classes Q and V, subgroups 7 and 8 shall include verifying the functionality of the device; these tests shall have been fault graded in accordance with MIL-STD-883, test method 5012 (see 1.5 herein).
- d. O/V (latch-up) tests shall be measured only for initial qualification and after any design or process changes which may affect the performance of the device. For device class M, procedures and circuits shall be maintained under document revision level control by the manufacturer and shall be made available to the preparing activity or acquiring activity upon request. For device classes Q and V, the procedures and circuits shall be under the control of the device manufacturer's TRB in accordance with MIL-I-38535 and shall be made available to the preparing activity or acquiring activity upon request. Testing shall be on all pins, on five devices with zero failures. Latch-up test shall be considered destructive. Information contained in JEDEC standard number 17 may be used for reference.
- e. Subgroup 4 (C_{IN} measurements) shall be measured only for initial qualification and after any process or design changes which may affect input capacitance. Capacitance shall be measured between the designated terminal and GND at a frequency of 1 MHz. Sample size is 15 devices with no failures, and all input terminals tested.

4.4.2 Group C inspection. The group C inspection end-point electrical parameters shall be as specified in table IIA herein. Delta limits shall apply only to subgroup 1 of group C inspection and shall consist of tests specified in table IIB herein.

4.4.2.1 Additional criteria for device class M. Steady-state life test conditions, method 1005 of MIL-STD-883:

- a. Test condition D. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1005.
- b. $T_A = +125^\circ\text{C}$, minimum.
- c. Test duration: 1,000 hours, except as permitted by method 1005 of MIL-STD-883.

4.4.2.2 Additional criteria for device classes Q and V. The steady-state life test duration, test condition and test temperature, or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-I-38535. The test circuit shall be maintained under document revision level control by the device manufacturer's TRB, in accordance with MIL-I-38535, and shall be made available to the acquiring or preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1005.

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TABLE IIA. Electrical test requirements. 1/ 2/ 3/ 4/ 5/ 6/ 7/

Line no.	Test requirements	Subgroups (in accordance with MIL-STD-883, method 5005, table I)	Subgroups (in accordance with MIL-I-38535, table III)	
		Device class M	Device class Q	Device class V
1	Interim electrical parameters (see 4.2)		1,7,9	1,7,9
2	Static burn-in (method 1015)	Required	Required	Required
3	Same as line 1			1* Δ
4	Dynamic burn-in (method 1015)	Not required	Not required	Not required
5	Final electrical parameters	1*,2,3,7*, 8A,8B,9,10, 11	1*,2,3,7*, 8A,8B,9,10, 11	1*,2,3,7*, 8A,8B,9, 10,11
6	Group A test requirements	1,2,3,4**,7, 8A,8B,9,10, 11	1,2,3,4**,7, 8A,8B,9,10, 11	1,2,3,4**,7, 8A,8B,9,10, 11
7	Group C end-point electrical parameters	2,3,7, 8A,8B	1,2,3,7, 8A,8B Δ	1,2,3,7, 8A,8B,9, 10,11 Δ
8	Group D end-point electrical parameters	2,3, 8A,8B	2,3, 8A,8B	2,3, 8A,8B
9	Group E end-point electrical parameters	1,7,9	1,7,9	1,7,9

1/ Blank spaces indicate tests are not applicable.

2/ Any or all subgroups may be combined when using high-speed testers.

3/ Subgroups 7 and 8 functional tests shall verify the functionality of the device.

4/ * indicates PDA applies to subgroup 1 and 7.

5/ ** see 4.4.1e.

6/ Δ indicates delta limit (see table IIB) shall be required where specified, and the delta values shall be computed with reference to the previous interim electrical parameters (see line 1).

7/ See 4.4.1d.

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4.4.3 Group D inspection. The group D inspection end-point electrical parameters shall be as specified in table IIA herein.

4.4.4 Group E inspection. Group E inspection is required only for parts intended to be marked as radiation hardness assured (see 3.5 herein). RHA levels for device classes Q and V shall be M, D, R, and H and for device class M shall be M and D.

- a. End-point electrical parameters shall be as specified in table II herein.
- b. For device class M, the devices shall be subjected to radiation hardness assured tests as specified in MIL-I-38535, appendix A, for the RHA level being tested. For device classes Q and V, the devices or test vehicle shall be subjected to radiation hardness assured tests as specified in MIL-I-38535 for the RHA level being tested. All device classes must meet the postirradiation end-point electrical parameter limits as defined in table I at $T_A = +25^\circ\text{C} \pm 5^\circ\text{C}$, after exposure, to the subgroups specified in table IIA herein.
- c. When specified in the purchase order or contract, a copy of the RHA delta limits shall be supplied.

TABLE IIB. Delta limits at $+25^\circ\text{C}$.

Parameter 1/	Device types
	ALL
I_{CCO} standby	± 1 mA of specified limit in table I.
I_{IL}	± 1 μA of specified limit in table I.

1/ The above parameter shall be recorded before and after the required burn-in and life tests to determine the delta.

4.5 Delta measurements for device classes Q and V. Delta measurements, as specified in table IIA, shall be made and recorded before and after the required burn-in screens and steady-state life tests to determine delta compliance. The electrical parameters to be measured, with associated delta limits are listed in table IIB. The device manufacturer may, at his option, either perform delta measurements or within 24 hours after burn-in perform final electrical parameter tests, subgroups 1, 7, and 9.

4.6 Programming procedures. The programming procedures shall be as specified by the device manufacturer and shall be made available upon request.

5. PACKAGING

5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-STD-883 (see 3.1 herein) for device class M and MIL-I-38535 for device classes Q and V.

6. NOTES

(This section contains information of a general or explanatory nature that may be helpful, but is not mandatory.)

6.1 Intended use. Microcircuits conforming to this drawing are intended for use for Government microcircuit applications (original equipment), design applications, and logistics purposes.

6.1.1 Replaceability. Microcircuits covered by this drawing will replace the same generic device covered by a contractor-prepared specification or drawing.

6.1.2 Substitutability. Device class Q devices will replace device class M devices.

6.2 Configuration control of SMD's. All proposed changes to existing SMD's will be coordinated with the users of record for the individual documents. This coordination will be accomplished in accordance with MIL-STD-973 using DD Form 1692, Engineering Change Proposal.

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6.3 Record of users. Military and industrial users shall inform Defense Electronics Supply Center when a system application requires configuration control and which SMD's are applicable to that system. DESC will maintain a record of users and this list will be used for coordination and distribution of changes to the drawings. Users of drawings covering microelectronic devices (FSC 5962) should contact DESC-EC, telephone (513) 296-6047.

6.4 Comments. Comments on this drawing should be directed to DESC-EC, Dayton, Ohio 45444, or telephone (513) 296-5377.

6.5 Abbreviations, symbols, and definitions. The abbreviations, symbols, and definitions used herein are defined in MIL-I-38535, MIL-STD-1331, and as follows:

V _{CC}	-----	+5.0 V SUPPLY VOLTAGE
GND	-----	GROUND
CCLK	-----	CONFIGURATION CLOCK
DONE	-----	DONE
PROGRAM	-----	PROGRAM
RCLK	-----	READ CLOCK
MO	-----	MODE 0
M1	-----	MODE 1
M2	-----	MODE 2
TDO	-----	TEST DATA OUTPUT
TDI	-----	TEST DATA IN
TCK	-----	TEST CLOCK
TMS	-----	TEST MODE SELECT
HDC	-----	HIGH DURING CONFIGURATION
LDC	-----	LOW DURING CONFIGURATION
INIT	-----	INIT
PGCK1-PGCK4	-----	PRIMARY GLOBAL INPUTS
RDY/BUSY	-----	During peripheral parallel mode configuration, this pin indicates when the chip is ready for another byte of data to be written into it. After configuration is complete, this pin becomes a user programmed I/O pin.
CS0	-----	CHIP SELECT, WRITE
CS1	-----	CHIP SELECT, WRITE
WS	-----	WRITE STROBE
RS	-----	READ STROBE
A0-A17	-----	ADDRESS
D0-D7	-----	DATA
DIN	-----	DATA INPUT
DOUT	-----	DATA OUTPUT
I/O	-----	INPUT/OUTPUT

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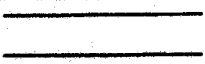
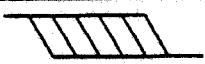


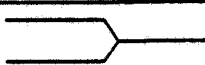
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6.5.1 Timing Limits. The table of timing values shows either a minimum or a maximum limit for each parameter. Input requirements are specified from the external system point of view. Thus, address setup time is shown as a minimum since the system must supply at least that much time (even though most devices do not require it). On the other hand, responses from the memory are specified from the device point of view. Thus, the access time is shown as a maximum since the device never provides data later than that time.

6.5.2 Waveforms.

Waveform symbol	Input	Output
	MUST BE VALID	WILL BE VALID
	CHANGE FROM H TO L	WILL CHANGE FROM H TO L
	CHANGE FROM L TO H	WILL CHANGE FROM L TO H
	DON'T CARE ANY CHANGE PERMITTED	CHANGING STATE UNKNOWN
		HIGH IMPEDANCE

6.6 One part - one part number system. The one part - one part number system described below has been developed to allow for transitions between identical generic devices covered by the three major microcircuit requirements documents (MIL-H-38534, MIL-I-38535, and 1.2.1 of MIL-STD-883) without the necessity for the generation of unique part numbers. The three military requirements documents represent different class levels, and previously when a device manufacturer upgraded military product from one class level to another, the benefits of the upgraded product were unavailable to the Original Equipment Manufacturer (OEM), that was contractually locked into the original unique part number. By establishing a one part number system covering all three documents, the OEM can acquire to the highest class level available for a given generic device to meet system needs without modifying the original contract parts selection criteria.

<u>Military documentation format</u>	<u>Example PIN under new system</u>	<u>Manufacturing source listing</u>	<u>Document</u>
New MIL-H-38534 Standard Microcircuit Drawings	5962-XXXXXZZ(H or K)YY	QML-38534	MIL-BUL-103
New MIL-I-38535 Standard Microcircuit Drawings	5962-XXXXXZZ(Q or V)YY	QML-38535	MIL-BUL-103
New 1.2.1 of MIL-STD-883 Standard Microcircuit Drawings	5962-XXXXXZZ(M)YY	MIL-BUL-103	MIL-BUL-103

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BUFFER SWITCHING CHARACTERISTICS

Test	Symbol	Conditions -55°C ≤ T _C ≤ +125°C 4.5 V ≤ V _{CC} ≤ 5.5 V unless otherwise specified	Group A subgroups	Device type	Limits		Unit
					Min	Max	
TBUF driving a horizontal Longline (L.L.) I to L.L. while T is low (buffer active)	T _{IO1}	See note.	N/A	ALL		13	ns
TBUF driving a horizontal Longline (L.L.) I going low to L.L. going from resistive pull up high to active low, (TBUF configured as open drain	T _{IO2}		N/A	ALL		13.5	ns
T going low to L.L. active and valid	T _{ON}		N/A	ALL		15.1	ns
T to L.L. inactive	T _{OFF}		N/A	ALL		3	ns
T going high to L.L. (inactive) with single pull-up resistor	T _{PUS}		N/A	ALL		36	ns
T going high to L.L. (inactive) with pair of pull-up resistors	T _{PUF}		N/A	ALL		17	ns

NOTE: These values are typical. They are not tested, characterized, or guaranteed but are derived from benchmark timing patterns.

6.7 Sources of supply.

6.7.1 Sources of supply for device classes Q and V. Sources of supply for device classes Q and V are listed in QML-38535. The vendors listed in QML-38535 have submitted a certificate of compliance (see 3.6 herein) to DESC-EC and have agreed to this drawing.

6.7.2 Approved sources of supply for device class M. Approved sources of supply for class M are listed in MIL-BUL-103. The vendors listed in MIL-BUL-103 have agreed to this drawing and a certificate of compliance (see 3.6 herein) has been submitted to and accepted by DESC-EC.

STANDARD MICROCIRCUIT DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444	SIZE A		5962-94730
		REVISION LEVEL	SHEET 36

STANDARDIZED MILITARY DRAWING SOURCE APPROVAL BULLETIN

DATE: 94-11-21

Approved sources of supply for SMD 5962-94730 are listed below for immediate acquisition only and shall be added to MIL-BUL-103 during the next revision. MIL-BUL-103 will be revised to include the addition or deletion of sources. The vendors listed below have agreed to this drawing and a certificate of compliance has been submitted to and accepted by DESC-EC. This bulletin is superseded by the next dated revision of MIL-BUL-103.

Standardized military drawing PIN	Vendor CAGE number	Vendor similar PIN 1/
5962-9473001MXX	68994	XC4013-10P6223B
5962-9473001MYX	68994	XC4013-10CB228B
5962-9473001MZX	68994	XC4013-10CB228B
5962-9473002MXX	68994	XC4013-6P6223B
5962-9473002MYX	68994	XC4013-6CB228B
5962-9473002MZX	68994	XC4013-6CB228B

1/ Caution. Do not use this number for item acquisition. Items acquired to this number may not satisfy the performance requirements of this drawing.

Vendor CAGE
number

68994

Vendor name
and address

Xilinx, Incorporated
2100 Logic Drive
San Jose, CA 95124

The information contained herein is disseminated for convenience only and the Government assumes no liability whatsoever for any inaccuracies in this information bulletin.